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Kind regards,

Team Nexperia

**20 November 2015** 

Product data sheet

# 1. General description

Unidirectional Transient Voltage Suppressor (TVS) in an ultra small leadless DSN1608-2 (SOD963) package, designed for transient overvoltage protection.

## 2. Features and benefits

- Rated peak pulse current: I<sub>PPM</sub> = 65 A (8/20 μs pulse)
- Rated peak pulse power: P<sub>PPM</sub> = 2100 W (8/20 μs pulse)
- Dynamic resistance R<sub>dyn</sub> = 0.1 Ω
- Reverse current: I<sub>RM</sub> = 1 nA
- Very low package height: 0.25 mm

# 3. Applications

- Power supply protection
- Industrial application
- Power management

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>PPM</sub>	peak pulse current	t <sub>p</sub> = 8/20 μs	[1][2]	-	-	65	Α
		t <sub>p</sub> = 10/1000 μs	[3][2]	-	-	10.1	Α
V <sub>RWM</sub>	reverse standoff voltage	T <sub>amb</sub> = 25 °C		-	-	12	V

- [1] In accordance with IEC 61000-4-5 and IEC 61643-321 (8/20 µs current waveform).
- [2] Measured from pin 1 to pin 2.
- [3] In accordance with IEC 61643-321 (10/1000 µs current waveform).





# **Pinning information**

#### Table 2. **Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		1 - 2
2	А	anode		sym035
			Transparent top view DSN1608-2 (SOD963)	

# **Ordering information**

#### **Ordering information** Table 3.

Type number	Package	ackage				
	Name	Description	Version			
PTVS12VZ1USKN	DSN1608-2	leadless ultra small package; 2 terminals; body 1.6 x 0.8 x 0.25 mm	SOD963			

#### Marking **7**.

#### Table 4. Marking codes

Type number	Marking code
PTVS12VZ1USKN	Z5

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
P <sub>PPM</sub>	peak pulse power	t <sub>p</sub> = 8/20 μs	[1][2]	-	2100	W
		t <sub>p</sub> = 10/1000 μs	[3][2]	-	180	W
I <sub>PPM</sub>	peak pulse current	t <sub>p</sub> = 8/20 μs	[1][2]	-	65	Α
		t <sub>p</sub> = 10/1000 μs	[3][2]	-	10.1	Α
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-40	125	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
ESD maxim	num ratings					
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2; contact discharge	[4][2]	-	30	kV
		IEC 61000-4-2; air discharge	[4][2]	-	30	kV

- 1] In accordance with IEC 61000-4-5 and IEC 61643-321 (8/20 μs current waveform).
- [2] Measured from pin 1 to pin 2.
- [3] In accordance with IEC 61643-321 (10/1000 µs current waveform).
- [4] Device stressed with ten non-repetitive ESD pulses.

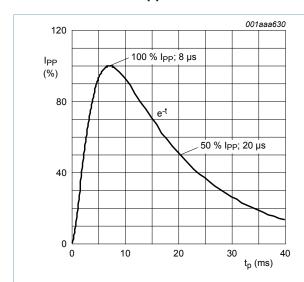


Fig. 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

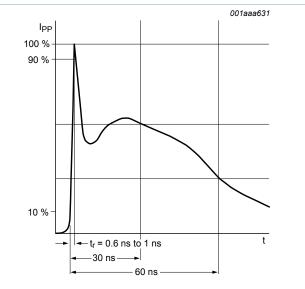
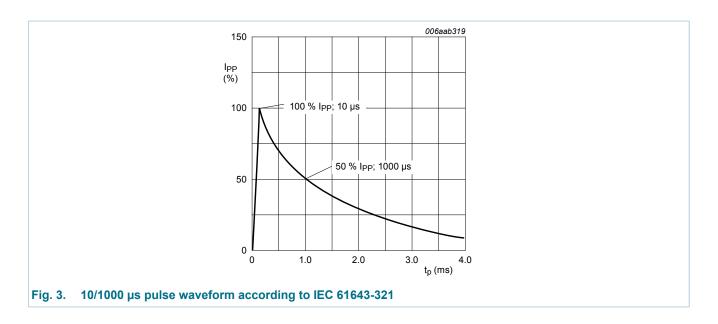


Fig. 2. ESD pulse waveform according to IEC 61000-4-2



# 9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{RWM}$	reverse standoff voltage	T <sub>amb</sub> = 25 °C		-	-	12	V
I <sub>RM</sub>	reverse leakage current	V <sub>RWM</sub> = 12 V; T <sub>amb</sub> = 25 °C	[1]	-	1	200	nA
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0 V; T <sub>amb</sub> = 25 °C		-	430	-	pF
$V_{BR}$	breakdown voltage	I <sub>R</sub> = 10 mA; T <sub>amb</sub> = 25 °C	[1]	13.3	14.4	15.4	V
V <sub>CL</sub>	clamping voltage	$I_{PPM}$ = 65 A; $T_{amb}$ = 25 °C; $t_p$ = 8/20 µs	[2][1]	-	25.9	32	V
		$I_{PPM}$ = 10.1 A; $T_{amb}$ = 25 °C; $t_p$ = 10/1000 µs	[3][1]	-	16.6	19.9	V
R <sub>dyn</sub>	dynamic resistance	I <sub>R</sub> = 10 A; T <sub>amb</sub> = 25 °C	[4][1]	-	0.1	-	Ω

- [1] Measured from pin 1 to 2.
- [2] In accordance with IEC 61000-4-5 and IEC 61643-321 (8/20 µs current waveform).
- [3] In accordance with IEC 61643-321 (10/1000 µs current waveform).
- [4] Non-repetitive current pulse, Transmission Line Pulse (TLP) t<sub>p</sub> = 100 ns; square pulse; ANSI / ESD STM5.5.1-2008.

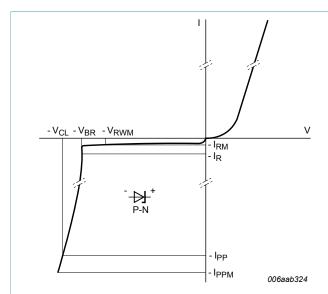


Fig. 4. V-I characteristics for a unidirectional TVS protection diode

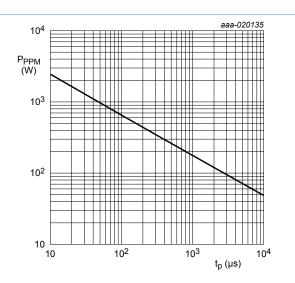


Fig. 5. Rated peak pulse power as a funtion of square pulse duration; typical values

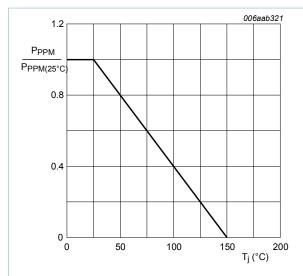


Fig. 6. Relative variation of rated peak pulse power as a function of junction temperature; typical values

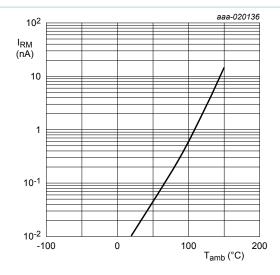


Fig. 7. Relative variation of reverse leakage current as a function of junction temperature; typical values

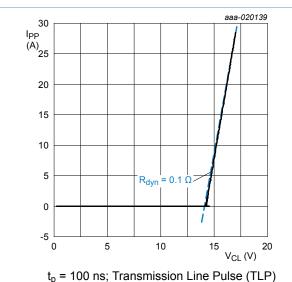


Fig. 8. Dynamic resistance with positive clamping voltage; typical values

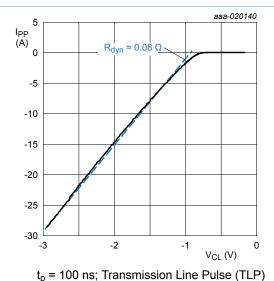
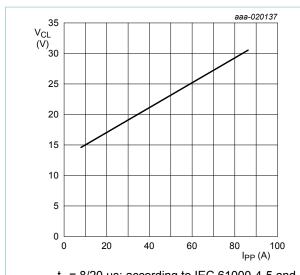


Fig. 9. Dynamic resistance with negative clamping voltage; typical values



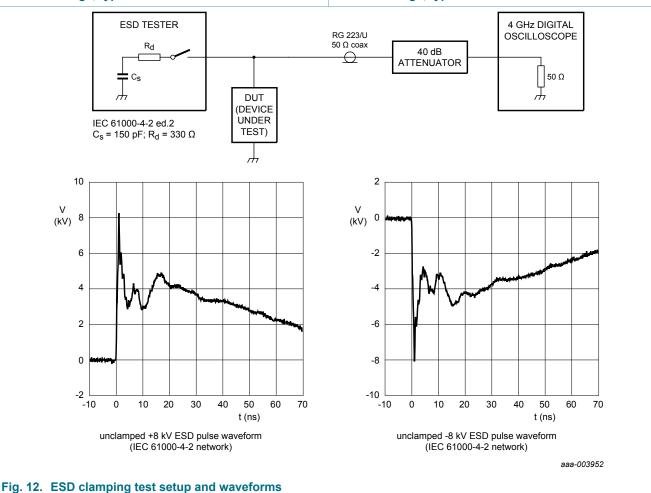
 $t_p$  = 8/20 µs; according to IEC 61000-4-5 and IEC 61643-321

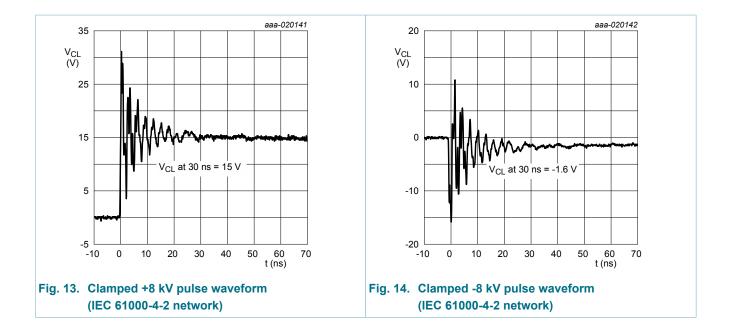
35 V<sub>CL</sub> (V) 30 25 20 15 10 5 0 40 80 120 160 200 I<sub>PP</sub> (A)

 $t_p$  = 8/20  $\mu s;$  according to IEC 61000-4-5 and IEC 61643-321

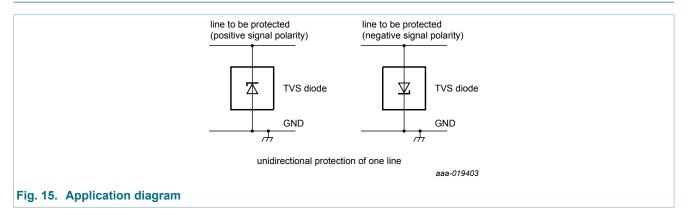
Fig. 10. Dynamic resistance with positive clamping voltage; typical values

Fig. 11. Dynamic resistance with negative clamping voltage; typical values

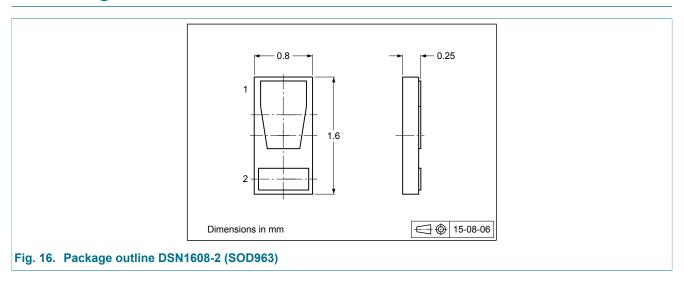




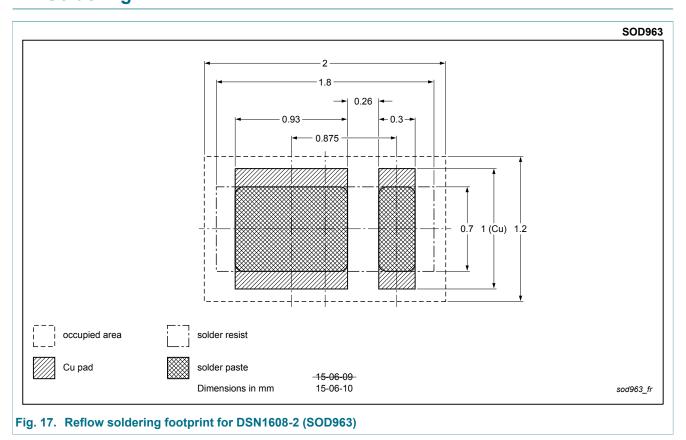
# 10. Application information



# 11. Package outline



# 12. Soldering



# 13. Revision history

### Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PTVS12VZ1USKN v.1	20151022	Preliminary data sheet	-	-
Modifications:	Product status char	iged		
PTVS12VZ1USKN v.2	20151120	Product data sheet	-	PTVS12VZ1USKN v.1

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#### 14.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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